## NSN 5961-01-365-6421

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-365-6421 **Inclosure Material:** Metal **Overall Length:** 1.166 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Anode **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.430 inches Thready Qty Per Inch (tpi): 32 **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1.5 gate trigger voltage, dc and 7.0 off-state voltage, dc **Current Rating Per Characteristic:** 50.00 milliamperes drain current preset **Special Features:** Junction pattern arrangement: pnpn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 2 uninsulated wire lead w/terminal lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

Fiig:

A110a0